- Output Current of 150 mA
- Reverse Battery Protection
- Very Low Quiescent Current
- 60-V Load-Dump Protection

i P

- Internal Short-Circuit Current Limiting
- Internal Thermal Overload Protection
- Mirror-Image Insertion Protection
- Reverse Transient Protection
- Direct Improved Replacement for National LM2931-5 and LM2931A-5

SILECT PACKAGE	D SMALL-OUTLINE PACKAGE	KC PACKAGE
(TOP VIEW)  INPUT COMMON OUTPUT  TO-226AA	(TOP VIEW)  OUTPUT   1   8   INPUT  COMMON   2   7   COMMON  COMMON   3   6   COMMON  NC   4   5   NC	(TOP VIEW)  OUTPUT COMMON INPUT  THE COMMON TERMINAL IS IN ELECTRICAL CONTACT WITH THE MOUNTING BASE  TO-220AB
ocı	Esse	° c -

### description

The LM2931-5AQ is a 3-terminal positive voltage regulator that provides a 5-V regulated output. It features the ability to source 150 mA of output current with an input-output differential of 0.6 V or less. Familiar regulator features such as current limit and thermal overload protection are also provided.

This device also has a low dropout voltage making it useful for certain battery applications. For example, because the low dropout voltage allows a longer battery discharge before the output falls out of regulation, the battery supplying the regulator input voltage may discharge to 5.6 V and still properly regulate the 5-V load voltage. Supporting this feature, the LM2931-5AQ protects both itself and the regulated system from reverse battery installation or 2-battery jumps. The very low quiescent current feature is especially useful in battery-powered applications.

Other protection features include line transient protection from load-dump of up to 60 V. In this case, the regulator shuts down to avoid damaging internal and external circuits. The LM2931-5AQ regulator is virtually immune to temporary mirror-image insertion.

The Q suffix indicates that the device is characterized for operation from -40°C to 125°C.

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# absolute maximum ratings over operating junction temperature range (unless otherwise noted)

Continuous input voltage
Transient input voltage: t = 1 s
Continuous reverse input voltage
Transient reverse input voltage: t = 100 ms
Continuous total dissipation (see Note 1) See Dissipation Rating Tables 1 and 2
Operating virtual junction temperature
Storage temperature range65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds

NOTE 1: To avoid exceeding the design maximum virtual junction temperature, these ratings should not be exceeded. Due to variation in individual device electrical characteristics and thermal resistance, the built-in thermal overload protection may be activated at power levels slightly above or below the rated dissipation.

#### DISSIPATION RATING TABLE 1 - FREE-AIR TEMPERATURE

PACKAGE	_	DERATING FACTOR ABOVE TA = 25°C	-
D	825 mW	6.6 mW/°C	165 mW
кс	2000 mW	16 mW/°C	400 mW
LP	775 mW	6.2 mW/°C	155 mW

#### DISSIPATION RATING TABLE 2 - CASE TEMPERATURE

PACKAGE	T <sub>C</sub> ≤ 25°C POWER RATING	DERATING FACTOR	DERATE ABOVE T <sub>C</sub>	T <sub>C</sub> = 125°C POWER RATING
D	1600 mW	29.4 mW/°C	96°C	735 mW
KC	20 W	0.18 W/°C	39°C	4.5 W
LP	1600 mW	28.6 mW/°C	94 °C	715 mW

### recommended operating conditions

	MIN	MAX	UNIT
Output current, IO		150	mA
Operating virtual junction temperature, Ty	-40	125	°C

## electrical characteristics at 25 °C virtual junction temperature, V<sub>I</sub> = 14 V (unless otherwise noted)

PARAMETER	TEST CONDITIONS†		TYP	MAX	UNIT	
Output voltage	$V_{I} = 6 \text{ V to } 26 \text{ V, } I_{O} \le 150 \text{ mA},$ $T_{J} = -40 ^{\circ}\text{C to } 125 ^{\circ}\text{C}$		5	5.25	٧	
Input regulation	$I_0 = 10 \text{ mA}$ $V_1 = 9 \text{ V to } 16 \text{ V}$ $V_1 = 6 \text{ V to } 26 \text{ V}$		4	10 30	m∨	
Ripple rejection	IO = 10 mA, f = 120 hz		80		dB	
Output regulation	I <sub>O</sub> = 5 mA to 150 mA		14	50	mV	
Output voltage long-term drift <sup>‡</sup>	IO = 10 mA, After 1000 h at T <sub>J</sub> = 125 °C		20		m∨	
D	l <sub>O</sub> = 10 mA		0.05	0.2	v	
Dropout voltage	I <sub>O</sub> = 150 mA		0.3	0.6	<b>v</b>	
Output noise voltage	$I_0 = 10 \text{ mA}, f = 10 \text{ Hz to } 100 \text{ kHz}$		500		μV rms	
Bias current	V <sub>I</sub> = 6 V to 26 V, I <sub>O</sub> = 10 mA, T <sub>J</sub> = -40°C to 125°C		0.4	1	mA	
	V <sub>I</sub> = 14 V, I <sub>O</sub> = 150 mA, T <sub>J</sub> = 25 °C		10	12	l	

<sup>†</sup> Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1-μF capacitor across the input to common and a 100-μF capacitor, with equivalent series resistance of less then 1 Ω, across the output to common.

<sup>&</sup>lt;sup>‡</sup> Since long-term drift cannot be measured on the individual devices prior to shipment, this specification is not intended to be a guarantee or warranty. It is an engineering estimate of the average drift to be expected from lot to lot.



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